

## Product Bulletin



### VM10EMD Series 10 Gb/s Drivers for M-Z Light Modulators or EMLs

These rugged, low-cost, high performance modulator-drivers utilize single-substrate COPLANAR MIC thin-film technology and state-of-art GaAs active devices. Systems using these drivers will achieve improved EYE opening, increased phase margin over time and temperature, higher extinction ratios, and lower BER.

Designed to drive Mach-Zehnder external modulators from ECL/SCFL inputs levels, they feature (a) a built-in bias terminal, (b) a “digitized” output for very high extinction ratios even when the input data is relatively “dirty”, (c) constant output over temperature, and (d) well-matched input and output impedances.

The output, though “saturated”, is electrically adjustable over a wide range. Typical output rise and fall times at nominal input and output approach 20ps. Pulse parameters such as rise and fall times and EYE opening at 10 Gb/s are guaranteed. Supplied with solderable contact pins for DC and removable SMA-F RF connectors.

#### Key features

- Advanced GaAs technology
- SCFL input levels, outputs up to 8.2 Vp-p
- Saturating mode “repairs” input deficiencies
- Adjustable output voltage Vp-p
- Rise and fall times <30 ps
- Guaranteed EYE and step responses
- Internal DC regulation and protection
- Small package
- Integrated bias terminal for modulator (High-Z, 3 mA max current)

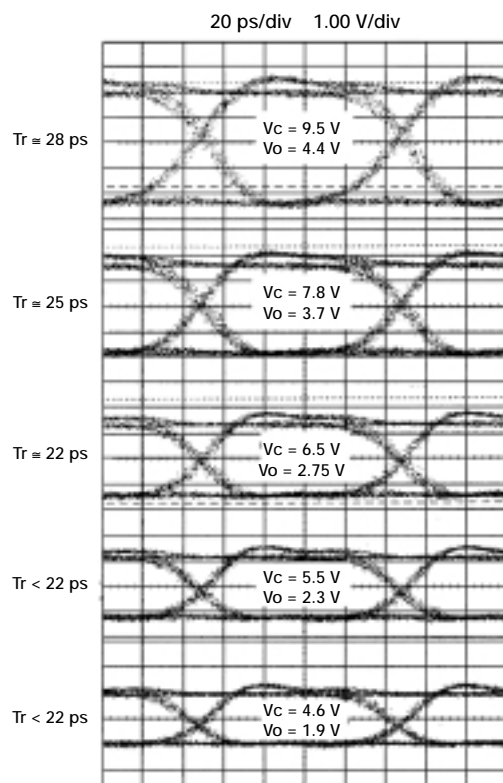
#### Applications

- Driver electronics for high quality 10 Gb/s terrestrial fiber-optic communication systems
- High speed data links

## Operating Characteristics

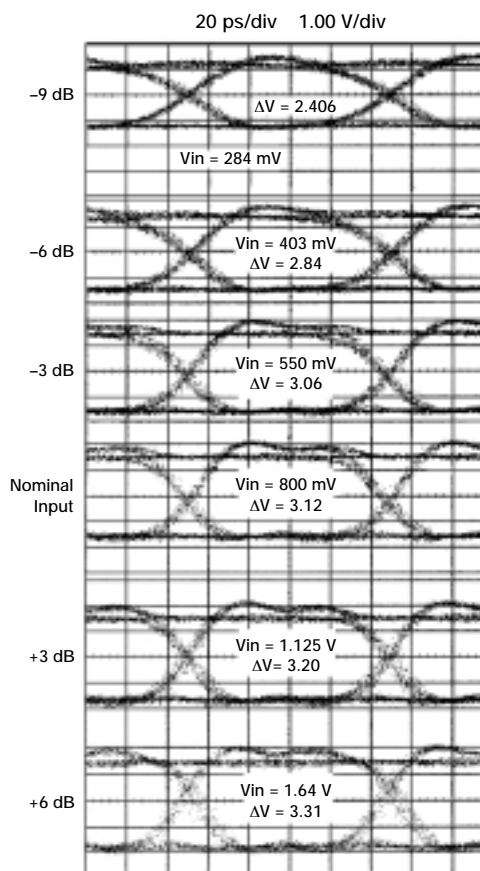
Control Voltage,  $V_c$ 

Varied to adjust  $V_{out}$   
 Input fixed at 0.9 Vp-p  
 Note transition times decrease to near 20 ps



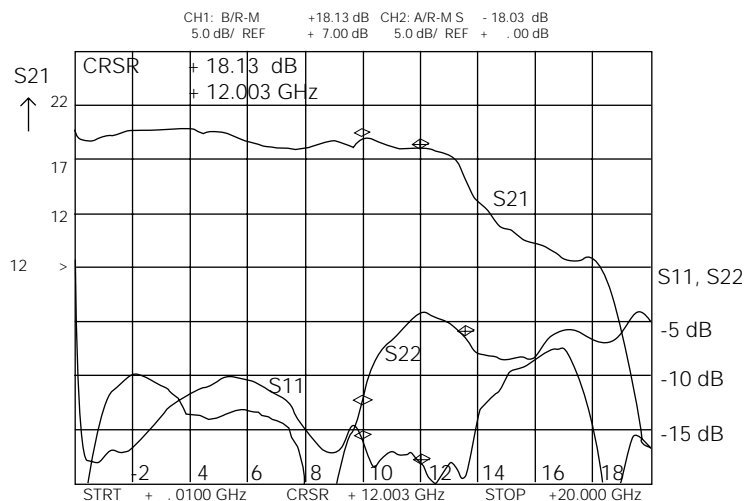
## Input Level

Varied from 284 mV to 1.64 V in 3 dB steps;  
 900 mV is nominal.  
 $V_c$  fixed at +7 V. Note output stays constant;  
 symmetry is good over a 15 dB input range.

Frequency Response  
(small signal)

Swept from .01-20 GHz

2GHz/DIV; 5dB/DIV



## 10 Gb/s Modulator Driver Performance Specifications

Model # VM10EMD - xxx	V <sub>in</sub> , p-p Volts p-p	V <sub>o</sub> V <sub>p-p</sub> <sup>1</sup>	3-dB BW GHz MIN <sup>2</sup>	I <sub>dc</sub> MAX/TYP mA@ +15V	I <sub>dc</sub> max mA@ -15V	V <sub>c</sub> Volts
- 418	0.9 - 1.1	4.0 - 7.2	9.0	400/320	20	0 to +15
- 425**	0.35 - .50	4.0 - 7.2	9.0	440/370	20	0 to +15

1. Adjustable electrically over at least this range.
2. Small-signal: operating bandwidth is larger due to saturation.

### Other Specifications

- Minimum EYE opening 85% at 10 Gbps, 95% TYP
- T<sub>r</sub>, T<sub>f</sub> < 35 ps, 28 ps TYP
- S<sub>11</sub> < -10 dB from 10 MHz to 8GHz; S<sub>22</sub> < -10 dB from 100 KHz to 8 GHz (see \*and\*\*)
- Input and output ports are DC blocked to ±20 V (capacitively coupled)
- MAX input level 2 V<sub>pp</sub>
- DC requirement +15 V; -15 V (internal regulation)
- Reverse voltage protection 50 V
- Output level control terminal: 0 to +V<sub>c</sub> at 10 mA MAX; V out largest at +V<sub>c</sub>
- Bias terminal ±10V MAX AT 3 mA MAX (High-Z, 1k-ohm)

### Reliability

High reliability screening, visual inspections and other screening per VMI Level III, including centrifuge, burn-in, temperature cycle, seal and final test are optional at extra cost.

### Factory Testing Technique

Pattern generator with 30 ps rise/fall time, 10 Gbs/s (NRZ), 2.0 V<sub>pp</sub> fixed output. Variable attenuator. Sampling oscilloscope with 12 GHz bandwidth (29ps). Input to DUT is (2<sup>n</sup>-1) word length. Observed T<sub>r</sub>, T<sub>f</sub> corrected for system speed, using sum of squares rule.

### Mechanical Data

Aluminum 6061T6, nickel plate. RF pins .015" dia. gold plated KOVAR with SMA-F replaceable shells. DC pins are 0.03" dia. Heat removal through case (conduction). Wire harness/connector available. All VM10EMD packages are 0.5" thick and 0.99" wide.

### Bias Terminal

The integrated bias terminal permits application of a DC voltage bias to the output of the device; this may be needed to operate modulators at 1/2 of V<sub>pi</sub>. The internal circuit is high impedance (about 1k-ohm) and will not pass current. Low-level, low-frequency AC may also be applied to this terminal.

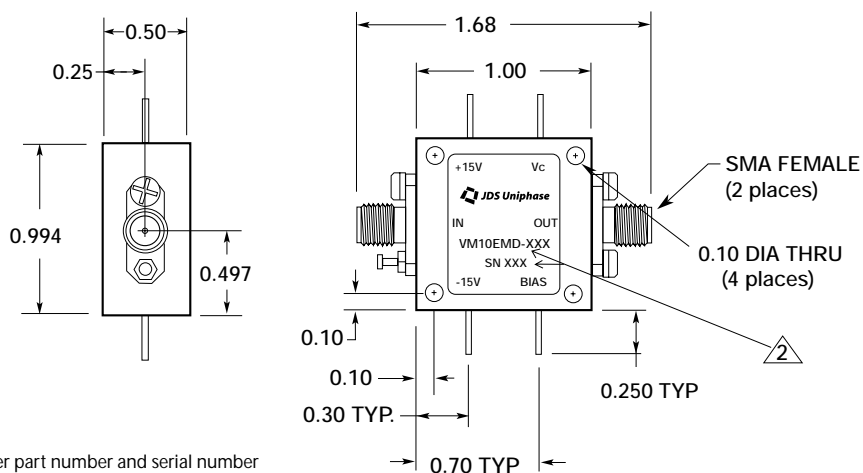
\* S<sub>22</sub>: < -8dB from 100 kHz to 8 GHz

\*\*S<sub>11</sub>: < -13 dB from 0.01-3GHz, < -10dB from 3 GHz to 10 GHz, S<sub>22</sub>: < -10 dB from 100kHz to 5.7 GHz

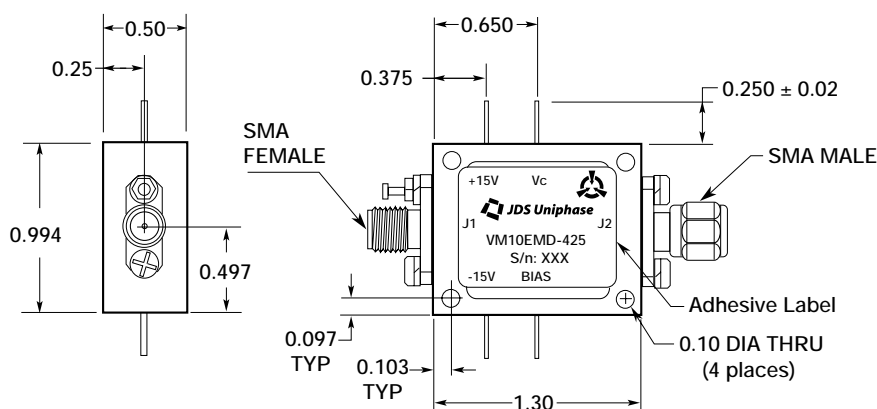
## Package Dimensions

Dimensions in inches except where indicated

**VM10EMD-418X**  
Standard Package



**VM10EMD-425X**  
Standard Package



## Ordering information

For more information on this or other products and their availability, please contact your local JDS Uniphase sales representative or JDS Uniphase directly at 732 465-2800, or by fax 732 465-2801, or via email at [sales.nj@us.jdsuniphase.com](mailto:sales.nj@us.jdsuniphase.com). Visit our Web site at [www.jdsuniphase.com](http://www.jdsuniphase.com).



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